

DFN0603 ESD

DFN0603 Plastic Package 1-Line,Bi-directional , ESD Protection Diode.

Stand-off voltage: $\pm 5\text{V}$ Max.

Transient protection for each line according to:

IEC61000-4-2(ESD): $\pm 30\text{kV}$ (contact).IEC61000-4-4 (EFT): 40A (5/50ns).IEC61000-4-5(surge): 8A (8/20 μs).Ultra-low capacitance: $C_J = 10\text{pF}$ typ.

Low leakage current.

Low clamping voltage: $V_{CL} = 10.0\text{V}$ typ. @ $I_{PP} = 16\text{A}$ (TLP).

Solid-state silicon technology.

HF Product.

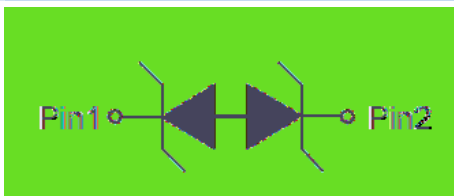
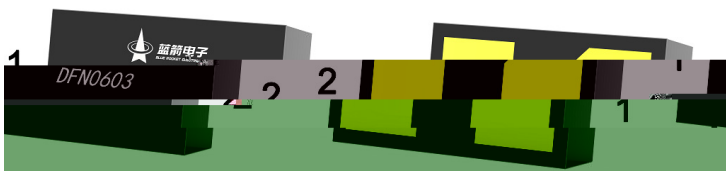
Cellular handsets.

Tablets.

Laptops.

Other portable devices.

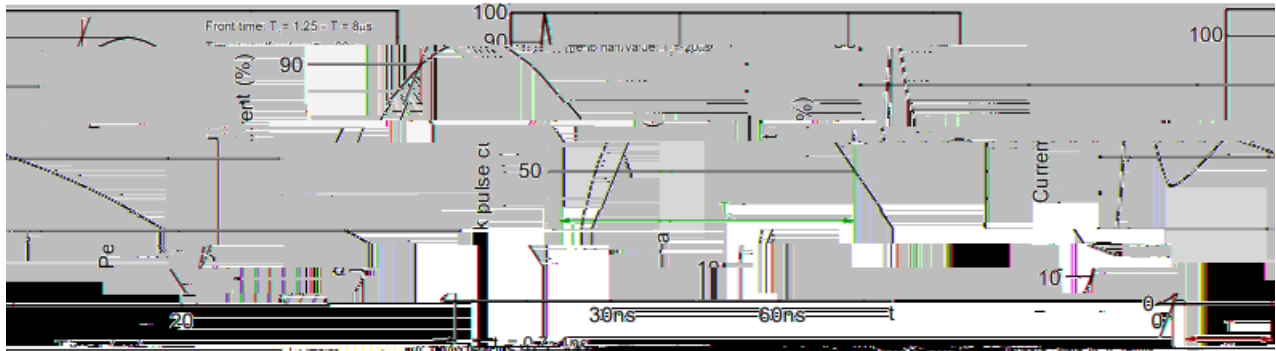
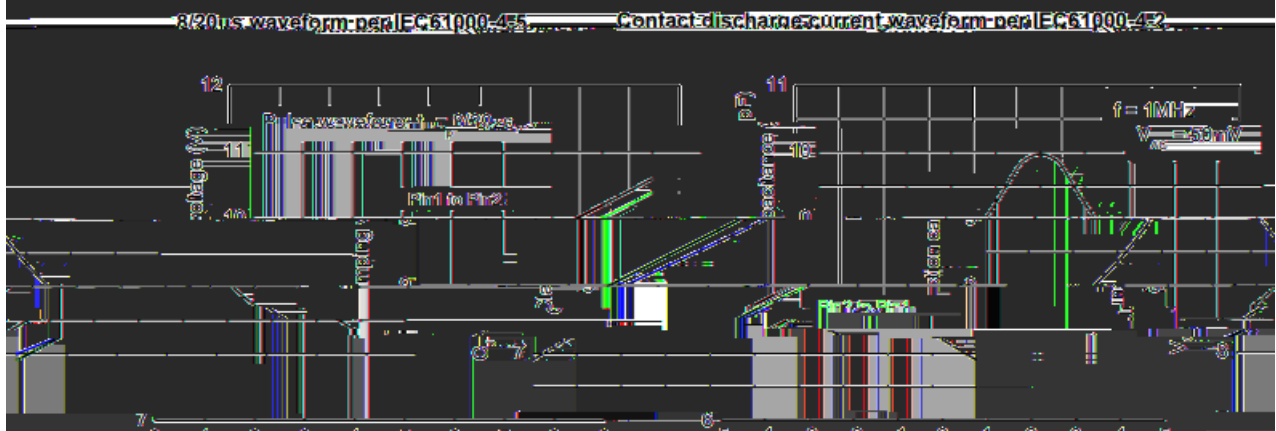
Network communication devices.

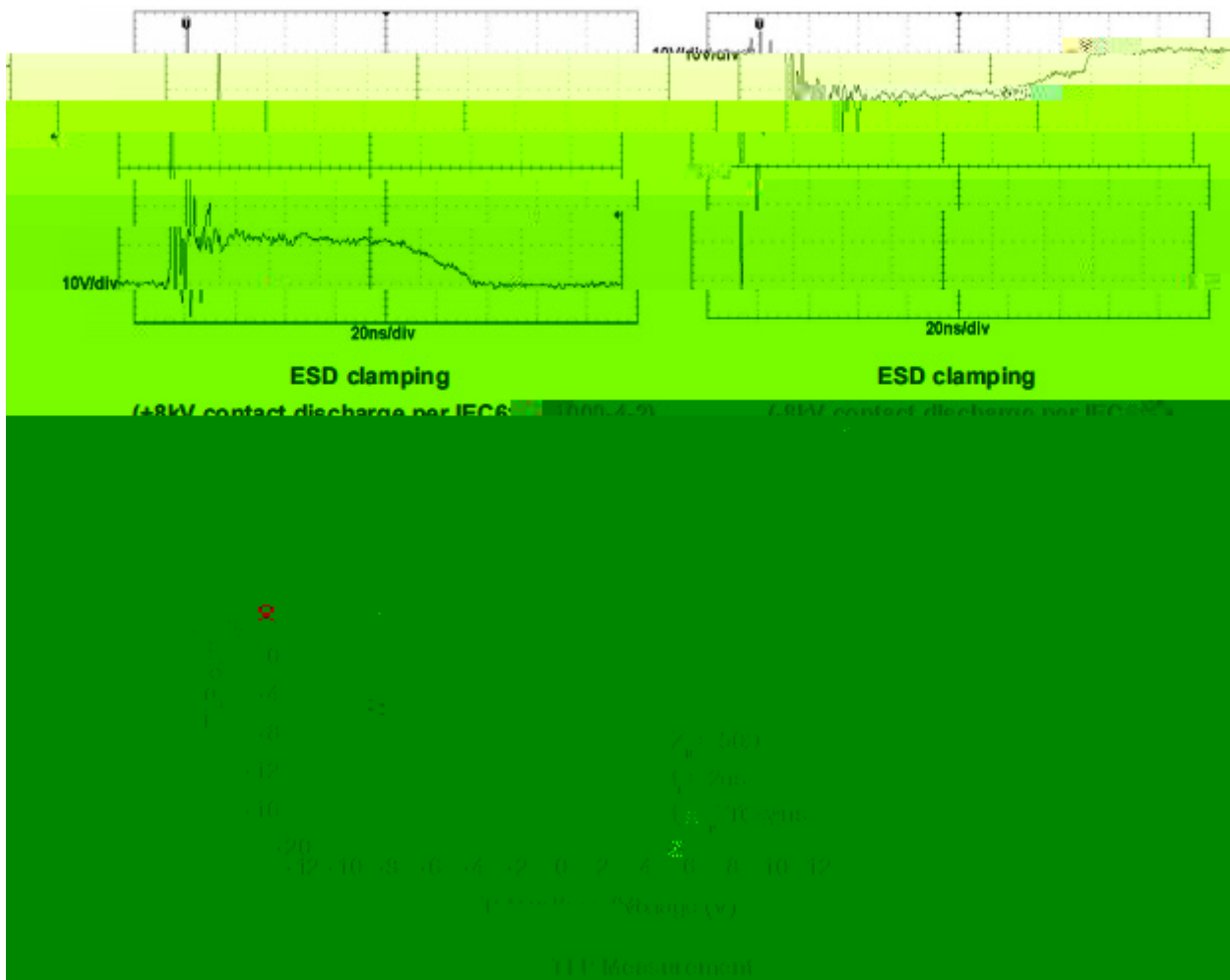


See Marking Instructions.

Parameter	Symbol	Rating	Unit
Peak Pulse Power($t_p = 8/20\mu s$)	P_{PK}	35	W
Peak Pulse Current($t_p = 8/20\mu s$)	I_{PP}	8	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	
Junction temperature	T_J	125	
Operating temperature	T_{OP}	-40~85	
Lead temperature	T_L	260	
Storage Temperature	T_{STG}	-55~+150	

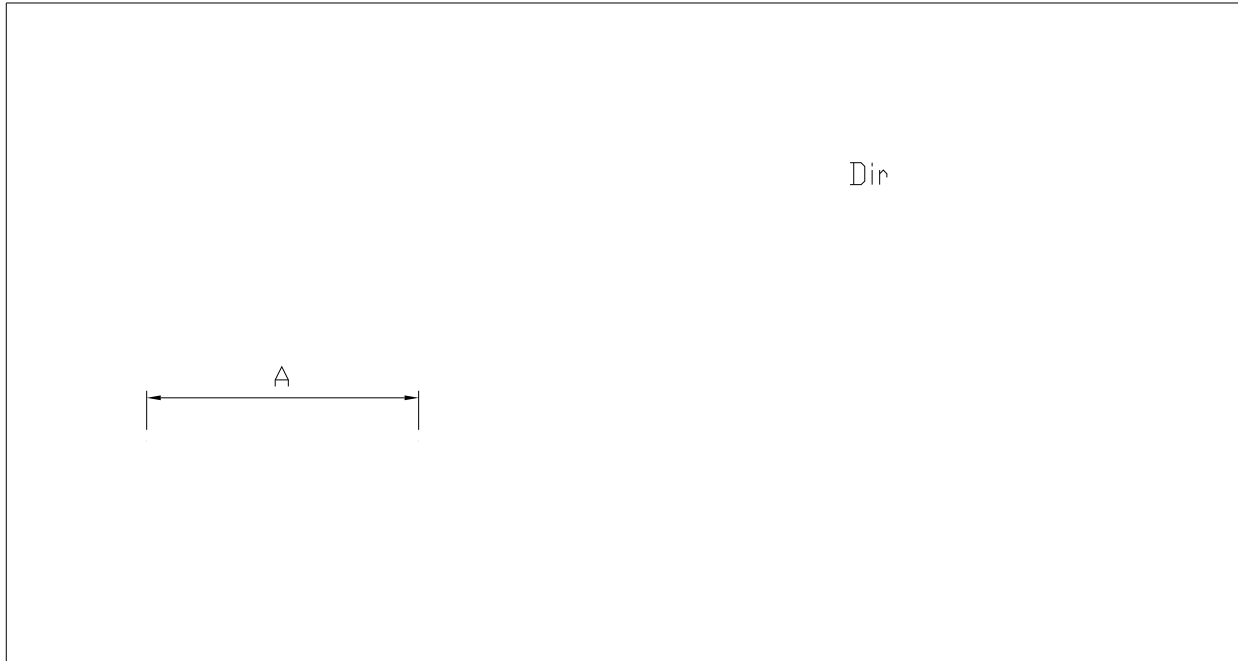
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
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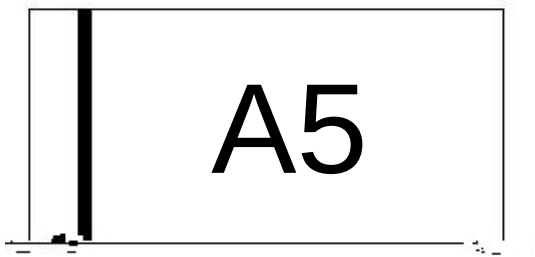


DFN0603

Unit:mm



Rev.02 202102



A5

Note

A5 Product Type Code

Temperature Profile for IR Reflow Soldering(Pb-Free)

- Note:

11501806090sec;1.Preheating:150~180, Time:60~90sec.

2245±55±0.5sec;2.Peak Temp.:245±5, Duration:5±0.5sec.

3210/sec.3. Cooling Speed: 2~10/sec.